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MEDIUM POWER AMPLIFIER APPLICATIONS.

FEATURES:

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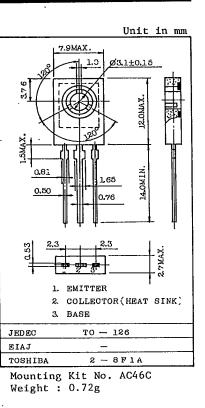
- Low Collector Saturation Voltage
  - : V<sub>CE(sat)</sub>=-0.32V (Typ.)
- Complementary to 2SC495 and 2SC496.

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MAXIMUM RATINGS (Ta=25°C)

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CHARACTERIS	SYMBOL	RATING	UNIT		
Collector-Base	2SA505	Vana	-60	v	
Voltage	2SA496	V <sub>СВО</sub>	-40		
Collector-Emitter Voltage	2SA505	VCEO	-50	v	
	2SA496	- VCEO	-30		
Emitter-Base Voltage		V <sub>EBO</sub>	-5	v	
Collector Current		IC	-1	A	
Emitter Current		IE	1	A	
Collector Power Dissipation		PC	1	W	
Junction Temperature		Tj 150		°C	
Storage Temperature Range		Tstg	$-55 \sim 150$	°C	



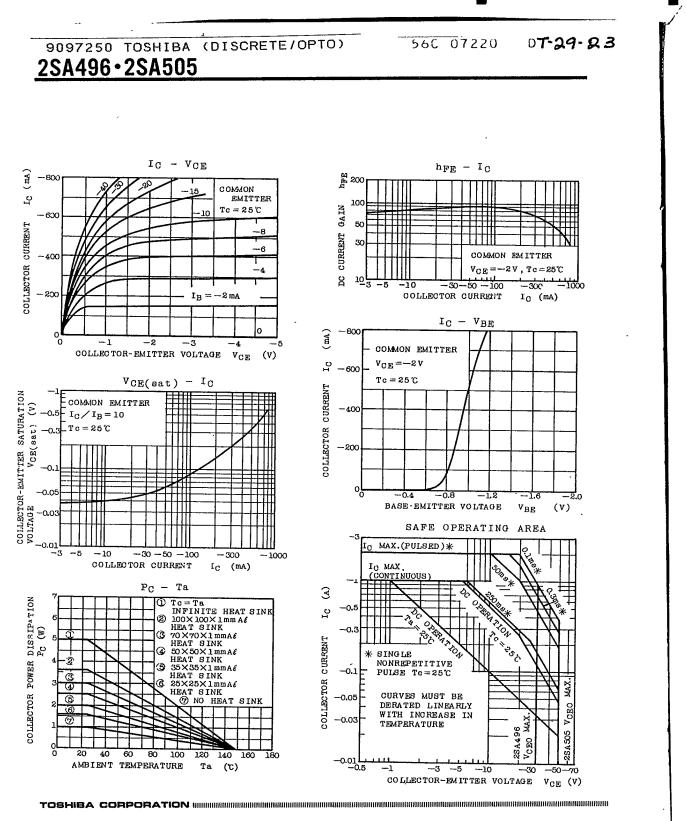
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ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current		ICBO	$V_{CB} = -30V$ , $I_{E} = 0$	-	-	-1	μΑ
Emitter Cut-off Current		IEBO	VEB=-5V, IC=0	-	-	-1	μA
Collector-Emitter Breakdown Voltage	2SA505	V(BR)CEO	I <sub>C</sub> =-10mA, I <sub>B</sub> =0	-50	-	-	v
	2SA496			-30	+	-	
Emitter-Base Breakdown Voltage		V(BR)EBO	I <sub>E</sub> =1mA, I <sub>C</sub> =0	5	-	-	v
DC Current Gain		(Note) hFE(1)	V <sub>CE</sub> =-2V, I <sub>C</sub> =-50mA	40	-	240	
		hFE(2)	V <sub>CE</sub> =-2V, I <sub>C</sub> =800mA	13	-	-	
Collector-Emitter Saturation Voltage		V <sub>CE(sat)</sub>	IC=-500mA, IB=-50mA	-	-0.32	-0.8	v
Base-Emitter Voltage		VBE	V <sub>CE</sub> =-2V, I <sub>C</sub> =-500mA	-	-	-1.3	v
Transition Frequency		fT	V <sub>CE</sub> =-10V, I <sub>C</sub> =-10mA	50	100	-	MHz
Collector Output Capacitance		Cob	$V_{CB}$ =-10V, I <sub>E</sub> =0, f=1MHz	-	20	-	pF

Note: hFE(1) Classification R :  $40 \sim 80$  0 :  $70 \sim 140$  Y :  $120 \sim 240$ 

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